

D44H11FP D45H11FP

Complementary power transistors

Features

- Low collector-emitter saturation voltage
- Fast switching speed

Applications

- Power amplifier
- Switching circuits

Description

These low voltage transistors are housed in fully isolated TO-220FP packages and form a complementary pair. They are manufactured in multi epitaxial planar technology for general purpose in linear and switching applications.

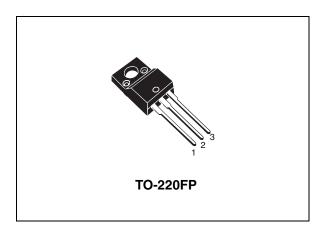


Figure 1. Internal schematic diagram

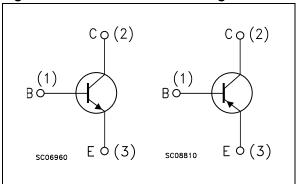


Table 1. Device summary

Order codes	Marking	Polarity	Package	Packaging
D44H11FP	D44H11FP	NPN	TO-220FP	Tube
D45H11FP	D45H11FP	PNP	TO-220FP	Tube

1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-emitter voltage (I _B = 0)	80	V
V _{EBO}	Emitter-base voltage (I _C = 0)	5	V
I _C	Collector current	10	Α
I _{CM}	Collector peak current	20	Α
P _{TOT}	Total dissipation at T _{case} = 25 °C	36	W
T _{STG}	Storage temperature	-55 to 150	°C
T _J	Max. operating junction temperature	150	°C

Note: For PNP types voltage and current values are negative.

Table 3. Thermal data

2/9

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	3.5	°C/W
R _{thJA}	Thermal resistance junction-ambient max	62.5	°C/W

2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test con	ditions	Min.	Тур.	Max.	Unit
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 30 mA		80	-		V
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 80 V			-	10	μΑ
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V			-	50	μΑ
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 8 A	I _B = 0.4 A		-	1	V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 8 A	$I_B = 0.8 A$		1	1.5	V
h _{FE} ⁽¹⁾	DC current gain	I _C = 2 A	V _{CE} = 1 V	60	-		
		I _C = 4 A	V _{CE} = 1 V	40	-		

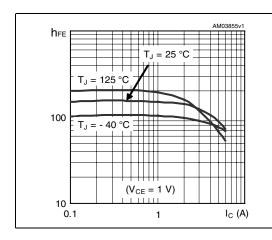
^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %.

Note: For PNP types voltage and current values are negative.

2.1 Electrical characteristics (curves)

Figure 2. DC current gain (NPN)

Figure 3. DC current gain (PNP)



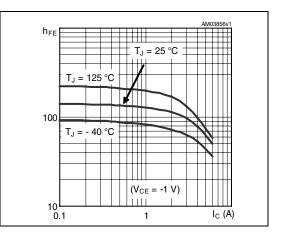
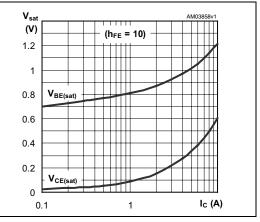


Figure 4. Saturation voltage (NPN)

V_{sat}
(V)
1.2
1
0.8
V_{BE(sat)}
0.6
0.4
0.2
V_{CE(sat)}
0.1
1
| I_C (A)

Figure 5. Saturation voltage (PNP)



3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 5. TO-220FP mechanical data

Dim.		mm	
	Min.	Тур.	Max.
Α	4.4		4.6
В	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.70
G	4.95		5.2
G1	2.4		2.7
Н	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2

A B Dia L6 F1 F2 F G G1 G1 T012510_Rev_K

Figure 6. TO-220FP drawing

8/9

4 Revision history

Table 6. Document revision history

Date	Revision	Changes
06-Aug-2009	1	Initial release.
22-Oct-2009	2	Document status promoted from preliminary data to datasheet, updated Ic current value on <i>Table 2: Absolute maximum ratings</i> , inserted new <i>Section 2.1: Electrical characteristics (curves)</i> and updated package mechanical data (see <i>Table 5</i> and <i>Figure 6</i>)
11-Mar-2011	3	Updated V _{CE(sat)} and V _{BE(sat)} maximum values on <i>Table 4: Electrical characteristics</i>

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2011 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by STMicroelectronics manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE158 NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460

2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 FMMTA92QTA

2N2369ADCSM 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E

US6T6TR 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR EMT2T2R MCH6102-TL-E

FP204-TL-E NJL0302DG 2N3583 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E NTE103 30A02MH-TL-E NSV40301MZ4T1G

NTE101 NTE13 NTE15